

# PA04 • PA04A

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# **FEATURES**

- HIGH INTERNAL DISSIPATION 200 WATTS
- HIGH VOLTAGE, HIGH CURRENT 200V, 20A
- HIGH SLEW RATE 50V/μS
- 4 WIRE CURRENT LIMIT SENSING
- LOW DISTORTION
- EXTERNAL SLEEP MODE CONTROL
- OPTIONAL BOOST VOLTAGE INPUTS
- EVALUATION KIT SEE EK04

# **APPLICATIONS**

- SONAR TRANSDUCER DRIVER
- LINEAR AND ROTARY MOTOR DRIVES
- YOKE/MAGNETIC FIELD EXCITATION
- PROGRAMMABLE POWER SUPPLIES TO  $\pm 95$ V
- AUDIO UP TO 400W

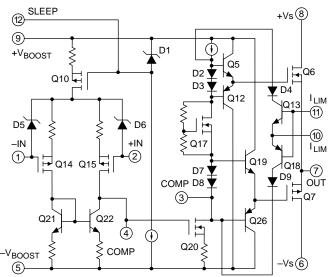
### DESCRIPTION

The PA04 is a high voltage MOSFET power operational amplifier that extends the performance limits of power amplifiers in slew rate and power bandwidth, while maintaining high current and power dissipation ratings.

The PA04 is a highly flexible amplifier. The sleep mode feature allows ultra-low quiescent current for standby operation or load protection by disabling the entire amplifier. Boost voltage inputs allow the small signal portion of the amplifier to operate at a higher voltage than the high current output stage. The amplifier is then biased to achieve close linear swings to the supply rails at high currents for extra efficient operation. External compensation tailors performance to user needs. A four wire sense technique allows precision current limiting without the need to consider internal or external milliohm parasitic resistance in the output line.

The JEDEC MO-127 12-pin Power Dip™ package (see Package Outlines) is hermetically sealed and isolated from the internal circuits. The use of compressible thermal washers will void product warranty.

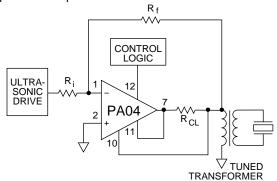
#### **EQUIVALENT SCHEMATIC**





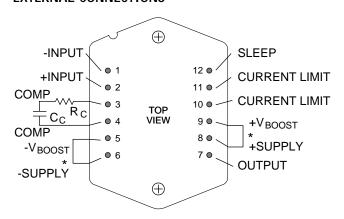
#### TYPICAL APPLICATION

The high power bandwidth and high voltage output of the PA04 allows driving sonar transducers via a resonant circuit including the transducer and a matching transformer. The load circuit appears resistive to the PA04. Control logic turns off the amplifier in sleep mode.



Sonar Transducer Driver

### **EXTERNAL CONNECTIONS**



### PHASE COMPENSATION

Gain	C <sub>c</sub>	$R_c$			
1	470pF	$120\Omega$			
>3	220pF	$120\Omega$			
≥10	100pF	$120\Omega$			

C<sub>c</sub> RATED FOR FULL SUPPLY VOLTAGE \*See "BOOST OPERATION" paragraph.

# PA04 • PA04A

ABSOLUTE MAXIMUM RATINGS SUPPLY VOLTAGE, +V<sub>s</sub> to -V<sub>s</sub> 200V

BOOST VOLTAGE SUPPLY VOLTAGE +20V

OPERATING TEMPERATURE RANGE, case -55 to +125°C

SPECIFICATIONS		PA04			PA04A			I
PARAMETER	TEST CONDITIONS 1	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
INPUT								
OFFSET VOLTAGE, initial OFFSET VOLTAGE, vs. temperature OFFSET VOLTAGE, vs. supply OFFSET VOLTAGE, vs. power	Full temperature range Full temperature range		5 30 15 30	10 50		2 10 * 10	5 30	mV μV/°C μV/V μV/W
BIAS CURRENT, initial BIAS CURRENT, vs. supply	T un temperature range		10 .01	50		5	20	pΑ pA/V
OFFSET CURRENT, initial INPUT IMPEDANCE, DC			10 10 <sup>11</sup>	50		5	20	pA Ω
INPUT CAPACITANCE COMMON MODE VOLTAGE RANGE COMMON MODE REJECTION, DC	Full temperature range Full temp. range, $V_{CM} = \pm 20V$	±V <sub>B</sub> -8	13 98		*	*		pF V dB
INPUT NOISE	100kHz BW, $R_s = 1KΩ$	00	10			*		μVrms
GAIN								
OPEN LOOP, @ 15Hz GAIN BANDWIDTH PRODUCT	Full temperature range, $C_c = 100pF$ $I_0 = 10A$	94	102 2		*	*		dB MHz
POWER BANDWIDTH  PHASE MARGIN	$R_L = 4.5\Omega$ , $V_O = 180V$ p-p $C_C = 100$ pF, $R_C = 120\Omega$ Full temperature range		90 60			*		kHz 。
	T un temperature range							
OUTPUT								
VOLTAGE SWING VOLTAGE SWING CURRENT, peak	$I_{O} = 15A$ $V_{BOOST} = Vs + 5V, I_{O} = 20A$	±V <sub>S</sub> -8.8 ±V <sub>S</sub> -6.8 20	±V <sub>S</sub> -7.5 ±V <sub>S</sub> -5.5		* *	*		V V A
SETTLING TIME to .1% SLEW RATE	$A_V = 1$ , 10V step, $R_L = 4\Omega$ $A_V = 10$ , $C_C = 100$ pF, $R_C = 120\Omega$	40	2.5 50			*		μs V/μs
CAPACITIVE LOAD RESISTANCE	Full temperature range, $A_v = +1$	10	2		*	*		nF Ω
POWER SUPPLY								
VOLTAGE CURRENT, quiescent, boost supply CURRENT, quiescent, total	Full temperature range	±15	±75 30 70 3	±100 40 90 5	*	* * *	* * *	V mA mA
CURRENT, quiescent, total, sleep mode THERMAL	Full temperature range		3	3				mA
	Full temperature range Ex COLI-			4		*	*	°C/W
RESISTANCE, AC, junction to case <sup>3</sup> RESISTANCE, DC, junction to case	Full temperature range, F>60Hz Full temperature range, F<60Hz		.3 .5	.4 .6		*	*	°C/W
RESISTANCE <sup>4</sup> , junction to air TEMPERATURE RANGE, case	Full temperature range Meets full range specification	-25	12	85	*	*	*	°C/W

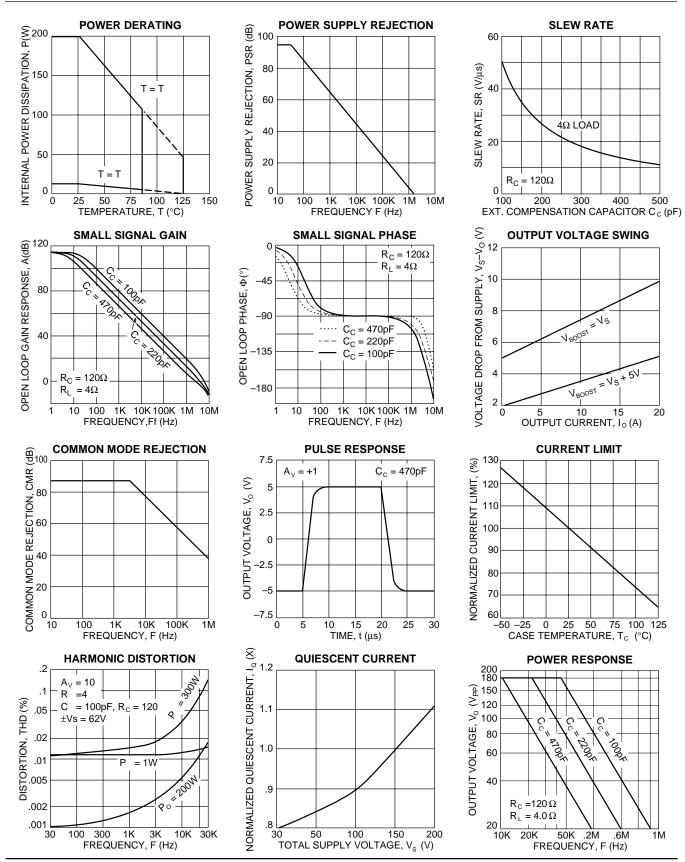
NOTES:

- \* The specification of PA04A is identical to the specification for PA04 in applicable column to the left.
- 1. Unless otherwise noted:  $T_C = 25^{\circ}C$ ,  $C_C = 470$  pF,  $R_C = 120$  ohms. DC input specifications are  $\pm$  value given. Power supply voltage is typical rating.  $\pm V_{BOOST} = \pm V_S$ .
- 2. Long term operation at the maximum junction temperature will result in reduced product life. Derate internal power dissipation to achieve high MTTF. For guidance, refer to the heatsink data sheet.
- 3. Rating applies if the output current alternates between both output transistors at a rate faster than 60 Hz.
- 4. The PA04 must be used with a heatsink or the quiescent power may drive the unit to junction temperatures higher than 150°C.

#### CAUTION

The PA04 is constructed from MOSFET transistors. ESD handling procedures must be observed.

The internal substrate contains beryllia (BeO). Do not break the seal. If accidentally broken, do not crush, machine, or subject to temperatures in excess of 850°C to avoid generating toxic fumes.



# PA04 • PA04A

#### **GENERAL**

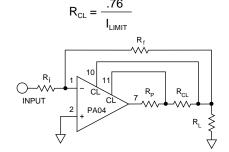
Please read the "General Operating Considerations" section, which covers stability, supplies, heatsinking, mounting, current limit, SOA interpretation, and specification interpretation. Additional information can be found in the application notes. For information on the package outline, heatsinks, and mounting hardware, consult the "Accessory and Package Mechanical Data" section of the handbook. The EK04 Evaluation Kit makes prototype circuits a snap by providing an EK04PC proto circuit board, MS05 mating socket, HS11 heatsink and hardware kit.

#### **CURRENT LIMIT**

Figure 1. Current Limit.

The two current limit sense lines are to be connected directly across the current limit sense resistor. For the current limit to work correctly pin 11 must be connected to the amplifier output side and pin 10 connected to the load side of the current limit resistor,  $R_{\text{CL}}$ , as shown in Figure 1. This connection will bypass any parasitic resistances, Rp, formed by sockets and solder joints as well as internal amplifier losses. The current limiting resistor may not be placed anywhere in the output circuit except where shown in Figure 1.

The value of the current limit resistor can be calculated as follows:

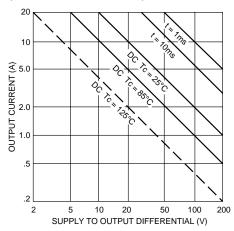


# SAFE OPERATING AREA (SOA)

The MOSFET output stage of this power operational amplifier has two distinct limitations:

- 1. The current handling capability of the MOSFET geometry and the wire bonds.
- 2. The junction temperature of the output MOSFETs.

The output stage is protected against transient flyback. However, for protection against sustained, high energy flyback, external fast-recovery diodes should be used.



#### SLEEP MODE OPERATION

In the sleep mode, pin 12 (sleep) is tied to pin 9 (+V<sub>BOOST</sub>). This disables the amplifier's internal reference and the amplifier shuts down except for a trickle current of 3 mA which flows into pin 12. Pin 12 should be left open if the sleep mode is not required.

Several possible circuits can be built to take advantage of this mode. In Figure 2A a small signal relay is driven by a logic gate. This removes the requirement to deal with the common mode voltage that exists on the shutoff circuitry since the sleep

mode is referenced to the  $+V_{\text{BOOST}}$  voltage. In Figure 2B, circuitry is used to level translate the sleep mode input signal. The differential input activates sleep mode with a differential logic level signal and allows common mode voltages to ±V<sub>BOOST</sub>.

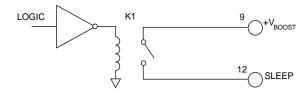
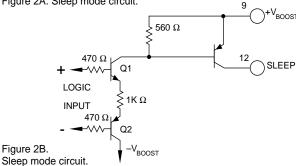


Figure 2A. Sleep mode circuit.



# **BOOST OPERATION**

With the  $V_{\text{BOOST}}$  feature the small signal stages of the amplifier are operated at higher supply voltages than the amplifier's high current output stage. +V<sub>BOOST</sub> (pin 9) and -V<sub>BOOST</sub> (pin 5) are connected to the small signal circuitry of the amplifier. +V<sub>s</sub> (pin 8) and -V<sub>s</sub> (pin 6) are connected to the high current output stage. An additional 5V on the V<sub>BOOST</sub> pins is sufficient to allow the small signal stages to drive the output transistors into saturation and improve the output voltage swing for extra efficient operation when required. When close swings to the supply rails is not required the  $+V_{\text{BOOST}}$  and  $+V_{\text{S}}$ pins must be strapped together as well as the  $-V_{BOOST}$  and  $-V_{S}$ pins. The boost voltage pins must not be at a voltage lower than the V<sub>S</sub> pins.

#### COMPENSATION

The external compensation components C<sub>c</sub> and R<sub>c</sub> are connected to pins 3 and 4. Unity gain stability can be achieved at any compensation capacitance greater than 330 pF with at least 60 degrees of phase margin. At higher gains more phase shift can be tolerated in most designs and the compensation capacitance can accordingly be reduced, resulting in higher bandwidth and slew rate. Use the typical operating curves as a guide to select C<sub>c</sub> and R<sub>c</sub> for the application.